NSN 5961-01-359-1813

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-359-1813 **Inclosure Material:** Ceramic **Overall Length:** 13.5 millimeters **Overall Height:** 1.5 millimeters **Overall Width:** 13.5 millimeters **Function For Which Designed:** Microwave **Internal Configuration:** Junction contact **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 25.0 collector to base voltage/static/emitter open and 15.0 collector to emitter voltage/static/base open and 1.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 150.00 amperes source cutoff current **Power Rating Per Characteristic:** 1.5 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No